

**FEATURES**

- \* 2.0 inch ( 50.80 mm) MATRIX HEIGHT
- \* LOW POWER REQUIREMENT
- \* HIGH BRIGHTNESS & HIGH CONTRAST
- \* SINGLE PLANE, WIDE VIEWING ANGLE
- \* SOLID STATE RELIABILITY
- \* 5x7 ARRAY WITH X-Y SELECT
- \* COMPATIBLE WITH USASCII AND EBCDIC CODES
- \* STACKABLE HORIZONTALLY
- \* CATEGORIZED FOR LUMINOUS INTENSITY

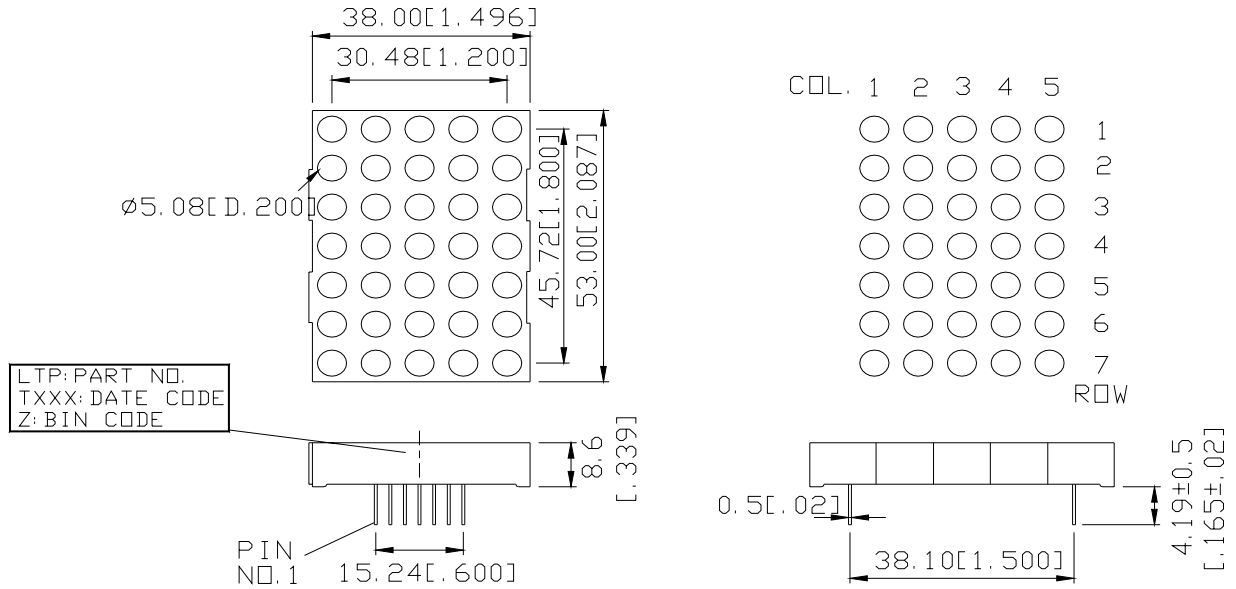
**DESCRIPTION**

The LPTL21157AFBK1 is a 2.0 inch (50.8 mm) matrix height 5x7 dot matrix display. This device uses AS-AlInGaP RED LED chips (AlInGaP epi on GaAsP substrate). The matrix display has black face and transparent dot.

**DEVICE**

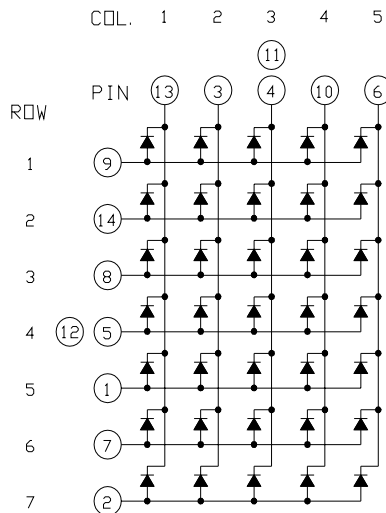
<b>PART NO.</b>	<b>DESCRIPTION</b>
AlInGaP RED	Cathode Column
LPTL21157AFBK1	Anode Row

## PACKAGE DIMENSIONS



- NOTES:** 1.All dimensions are in millimeters. Tolerance is  $\pm 0.25$  mm (0.01") unless otherwise noted.  
 2.Pin tip's shift tol. is  $\pm 0.4$ mm

## INTERNAL CIRCUIT DIAGRAM



**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	ANODE ROW 5
2	ANODE ROW 7
3	CATHODE COLUMN 2
4	CATHODE COLUMN 3
5	ANODE ROW 4
6	CATHODE COLUMN 5
7	ANODE ROW 6
8	ANODE ROW 3
9	ANODE ROW 1
10	CATHODE COLUMN 4
11	CATHODE COLUMN 3
12	ANODE ROW 4
13	CATHODE COLUMN 1
14	ANODE ROW 2

## ABSOLUTE MAXIMUM RATING

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per Dot	40	mW
Peak Forward Current Per Dot ( Frequency 1Khz, 18% duty cycle)	90	mA
Average Forward Current Per Dot	15	mA
Forward Current Derating from 25 <sup>0</sup> C	0.2	mA/ <sup>0</sup> C
Reverse Voltage Per Dot	5	V
Operating Temperature Range	-35 <sup>0</sup> C to +85 <sup>0</sup> C	
Storage Temperature Range	-35 <sup>0</sup> C to +85 <sup>0</sup> C	
Soldering Conditions : 1/16 inch below seating plane for 3 seconds at 260 <sup>0</sup> C , or temperature of unit (during assembly) not over max. temperature rating above		

## ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25<sup>0</sup>C

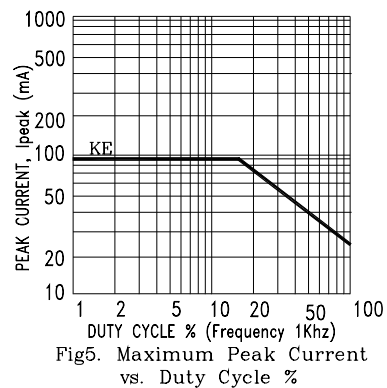
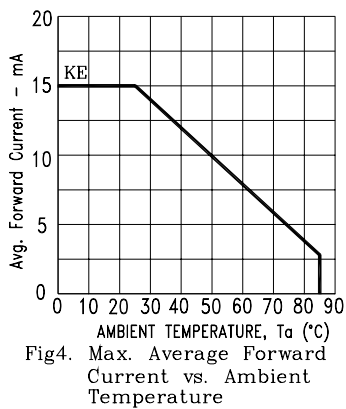
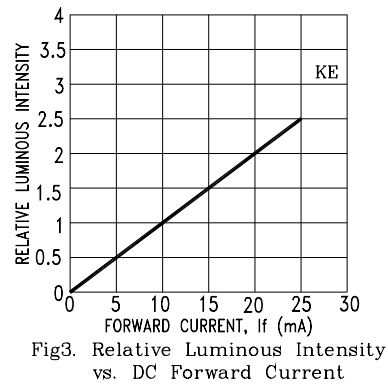
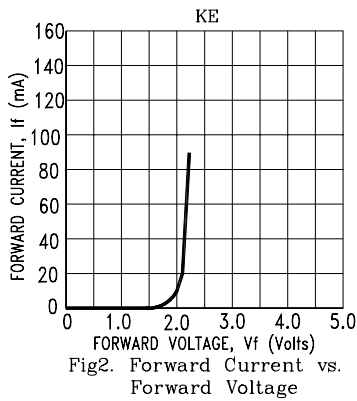
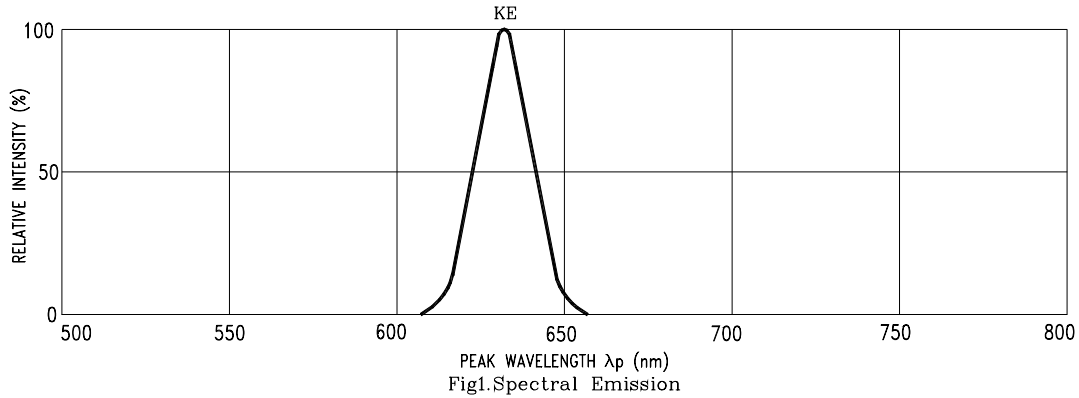
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>		3003		μcd	I <sub>p</sub> =2mA 1/16Duty
Peak Emission Wavelength	λ <sub>p</sub>		632		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		20		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		624		nm	I <sub>F</sub> =20mA
Forward Voltage any Dot	V <sub>F</sub>		2.05	2.6	V	I <sub>F</sub> =20mA
Reverse Current any Dot	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

BIN GRADE	K2	L1	L2	M1
RANGE	21.1 : 34.0	34.1 : 54.4	54.5 : 87.0	54.5 : 87.0

**TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES**

(25°C Ambient Temperature Unless Otherwise Noted)



NOTE : KE=AlInGaP RED